

Description

The AON6360-HXY uses advanced trench technology

to provide excellent $R_{\text{DS}(\text{ON})},$ low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

V_{DS} = 30V I_D =120A

 $R_{DS(ON)} < 4.4m$ V_{GS}=10V

Application

Battery protection

Load switch

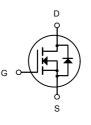
Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Markir	Marking 120N03 XXX YYYY		Qty(PCS)	
AON6360-HXY	DFN5X6-8L	120N0			5000	
bsolute Maximu	m Ratings (T _c =25	℃unless otherwise r	noted)			
Symbol		Parameter		Rating		Units
VDS	Drai	n-Source Voltage			V	
Vgs	Gate-Source Voltage ±20			20	V	
I₀@Tc=25°C	Continuous Drain Current, V _{GS} @ 10V ^{1,6} 120			20	А	
I _D @T _C =100°C	Continuous D	rain Current, V _{GS} @ 10V ¹	,6		А	
Ідм	Puls	Pulsed Drain Current ² 320		320	А	
EAS	Single Pulse Avalanche Energy ³		180		mJ	
las	Avalanche Current			60		A
P _D @T _C =25°C	Total Power Dissipation ⁴			187		W
Тятд	Storage	Temperature Range		-55 to 150		°C
TJ	Operating Ju	nction Temperature Rang	e	-55 to 150		°C
R ₀ JA	Thermal Res	stance Junction-Ambient	1	62		
Rejc	Thermal Re	esistance Junction-Case ¹	ase ¹ 1.1 °C/			°C/W







N-Channel MOSFET

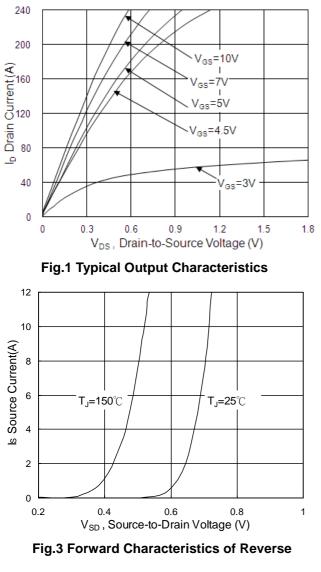


Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V
₽BVbss/₽TJ	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =1mA		0.014		V/°C
		V _{GS} =10V , I _D =30A		3.5	4.4	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =15A		4.6	5.8	mΩ
VGS(th)	Gate Threshold Voltage		1.2		2.5	V
$\mathbb{P}V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	−− V _{GS} =V _{DS} , I _D =250uA		-4		mV/°C
		V _{DS} =24V , V _{GS} =0V , T _J =25°C			1	
IDSS	Drain-Source Leakage Current	V _{DS} =24V , V _{GS} =0V , T _J =55°C			5	uA
lgss	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	luctance V _{DS} =5V , I _D =30A		50		S
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.7		Ω
Qg	Total Gate Charge (4.5V)			56.9		
Qgs	Gate-Source Charge V _{DS} =15V , V _{GS} =10V , I _D =1			13.8		nC
Qgd	Gate-Drain Charge			23.5		
Td(on)	Turn-On Delay Time			20.1		
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V ,		6.3		
Td(off)	Turn-Off Delay Time	—R _G =3.3 , I _D =1A		124.6		ns
T _f	Fall Time			15.8		
Ciss	Input Capacitance			4345		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		340		pF
Crss	Reverse Transfer Capacitance	-		225		
ls	Continuous Source Current ^{1,6}	$V_G=V_D=0V$, Force Current			85	A
Vsd	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1.2	V

Electrical Characteristics (TJ=25 °C, unless otherwise noted)



Typical Characteristics



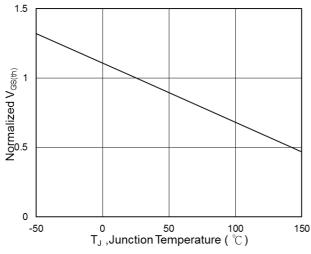


Fig.5 Normalized $V_{GS(th)}$ v.s T_J

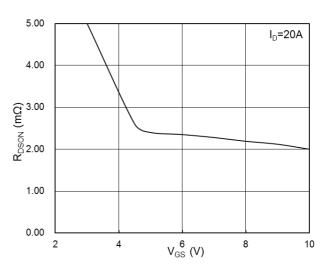


Fig.2 On-Resistance v.s Gate-Source

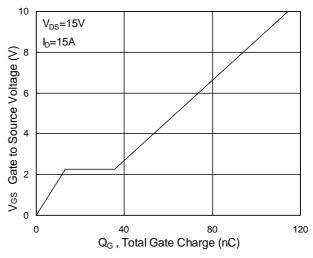


Fig.4 Gate-Charge Characteristics

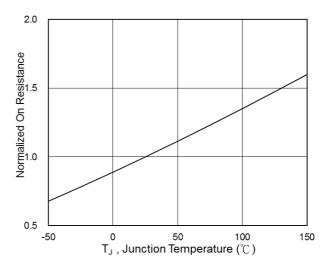


Fig.6 Normalized R_{DSON} v.s T_J



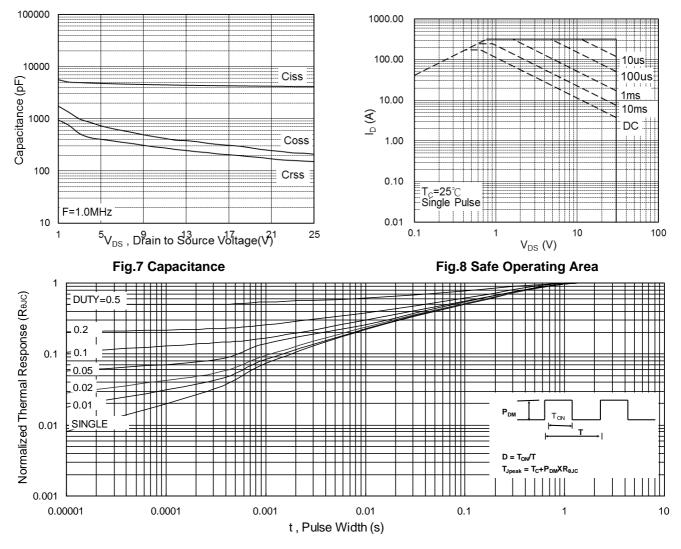


Fig.9 Normalized Maximum Transient Thermal Impedance

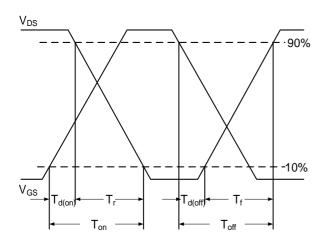
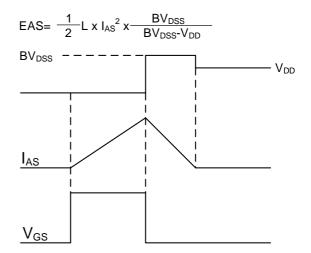


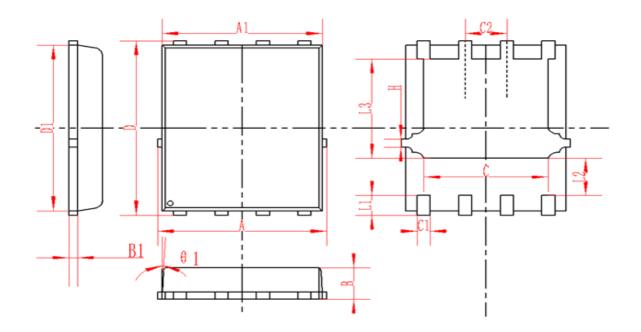
Fig.10 Switching Time Waveform







DFN5X6-8L Package Information



SYMBOL	MM			INCH				
	MIN	NOM	MAX	MIN	NOM	MAX		
А	4.95	5	5.05	0.195	0.197	0.199		
A1	4.82	4.9	4.98	0.190	0.193	0.196		
D	5.98	6	6.02	0.235	0.236	0.237		
D1	5.67	5.75	5.83	0.223	0.226	0.230		
В	0.9	0.95	1	0.035	0.037	0.039		
B1	0.254REF			0.010REF				
С	3.95	4	4.05	0.156	0.157	0.159		
C1	0.35	0.4	0.45	0.014	0.016	0.018		
C2	1.27TYP			0.5TYP				
θ1	8°	10°	12°	8°	10°	12°		
L1	0.63	0.64	0.65	0.025	0.025	0.026		
L2	1.2	1.3	1.4	0.047	0.051	0.055		
L3	3.415	3.42	3.425	0.134	0.135	0.135		
Н	0.24	0.25	0.26	0.009	0.010	0.010		



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